



1N5820 THRU 1N5822

3.0 AMPS. Schottky Barrier Rectifiers

| | |
|--|---|
| | Voltage Range 20 to 40 Volts Current 3.0 Amperes |
| <p>Features</p> <ul style="list-style-type: none"> ✧ Low forward voltage drop ✧ High current capability ✧ High reliability ✧ High surge current capability <p>Mechanical Data</p> <ul style="list-style-type: none"> ✧ Cases: DO-201AD molded plastic ✧ Epoxy: UL 94V-O rate flame retardant ✧ Lead: Axial leads, solderable per MIL-STD-202, Method 208 guaranteed ✧ Polarity: Color band denotes cathode end ✧ High temperature soldering guaranteed: 260°C/10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension ✧ Weight: 1.10 grams | <p>DO-201AD</p> <p style="text-align: center;">Dimensions in inches and (millimeters)</p> |

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

| Type Number | Symbol | 1N5820 | 1N5821 | 1N5822 | Units |
|---|----------------|-------------|--------|--------|---------------------------|
| Maximum Recurrent Peak Reverse Voltage | V_{RRM} | 20 | 30 | 40 | V |
| Maximum RMS Voltage | V_{RMS} | 14 | 21 | 28 | V |
| Maximum DC Blocking Voltage | V_{DC} | 20 | 30 | 40 | V |
| Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @ $T_L = 90^\circ\text{C}$ | $I_{(AV)}$ | 3.0 | | | A |
| Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method) | I_{FSM} | 80 | | | A |
| Maximum Instantaneous Forward Voltage @ 3.0A | V_F | 0.475 | 0.500 | 0.525 | V |
| Maximum Instantaneous Forward Voltage @ 9.0A | V_F | 0.850 | 0.900 | 0.950 | V |
| Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=100^\circ\text{C}$ | I_R | 2.0 20 | | | mA mA |
| Typical Thermal Resistance (Note 1) | $R\theta_{JA}$ | 40 | | | $^\circ\text{C}/\text{W}$ |
| Typical Junction Capacitance (Note 2) | C_j | 200 | | | pF |
| Operating Temperature Range | T_J | -65 to +125 | | | $^\circ\text{C}$ |
| Storage Temperature Range | T_{STG} | -65 to +125 | | | $^\circ\text{C}$ |

Notes: 1. Mount on Cu-Pad Size 16mm x 16mm on P.C.B.

2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

RATINGS AND CHARACTERISTIC CURVES (1N5820 THRU 1N5822)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

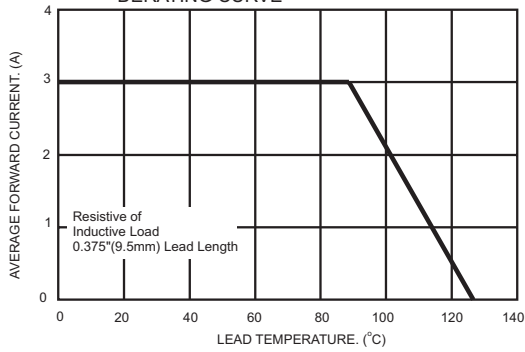


FIG.2- TYPICAL REVERSE CHARACTERISTICS

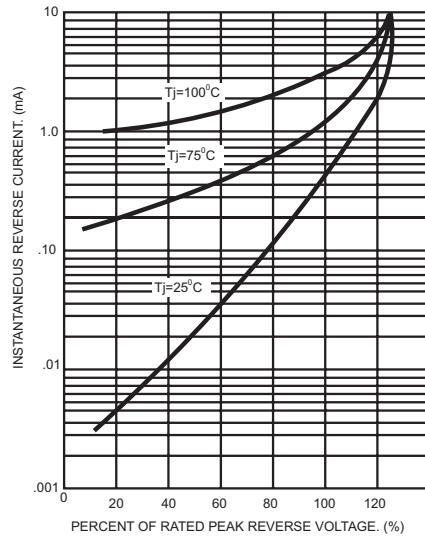


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

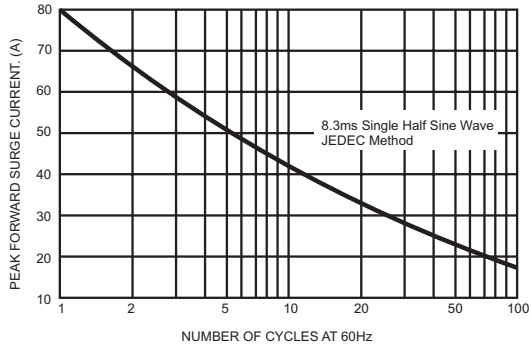


FIG.4- TYPICAL FORWARD CHARACTERISTICS

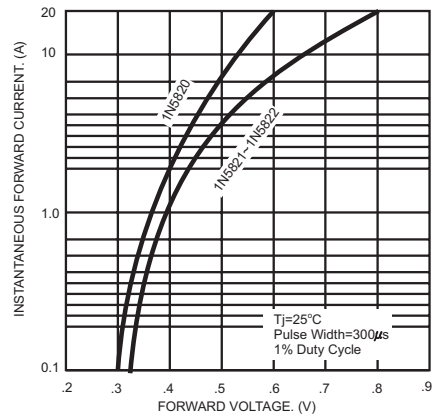


FIG.5- TYPICAL JUNCTION CAPACITANCE

